Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.260 inches	
Terminal Length:	
1.500 inches	
Overall Diameter:	
0.370 inches	
Internal Configuration:	
Junction contact	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
То-9	
Electrode Internally-electrically Connected To Case:	
Collector	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
5.0 knee voltage	
Current Rating Per Characteristic:	
220.00 milliamperes source cutoff current preset	
Power Rating Per Characteristic:	
1.25 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius ambient air	
Special Features:	
Junction pattern arrangement: pnpn	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Filg:	
A110a0	
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